Transport properties of Tl$_2$Ba$_2$CaCu$_2$O$_8$ weak links on LaAlO$_3$ bicrystal substrates

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Josephson junctions and dc superconducting quantum interference devices (SQUIDs) have been fabricated in ex situ epitaxial Tl$_2$Ba$_2$CaCu$_2$O$_8$ films on bicrystal LaAlO$_3$ substrates with symmetric 32° [001] tilt grain boundaries. The critical temperature $T_c$, of the junctions was in the range 105–107 K and the critical current densities at 77 K varied between $3 \times 10^2$ and $3 \times 10^4$ A/cm$^2$, two or three orders of magnitude less than those of the film. The $I$–$V$ curves are described by a resistively shunted junction model. Close to $T_c$, the temperature dependence of the critical current was described by $(1-T/T_c)^2$. The flux noise spectra $S_{\Phi}(f)$ of dc SQUIDs were measured in the locked-loop regime with constant current bias at temperatures up to 94 K. The white noise level was $50\mu$Φ$0/\sqrt{\text{Hz}}$ at 77 K. The crossover frequency to $1/f$ noise was low, about 5 Hz, and the flux noise level at 1 Hz was $440\mu$Φ$0/\sqrt{\text{Hz}}$. © 1996 American Institute of Physics.

I. INTRODUCTION

Grain boundaries in high-$T_c$ superconductors (HTSs) play a very important role in the formation of Josephson junctions. Artificial grain boundaries exhibiting the Josephson effect in HTS thin films may be produced using either the bicrystal substrate, 1 the step edge, 2 or the biepitaxial process. 3 Compared with other types of grain-boundary structures, the bicrystal structure is straightforward to prepare and is relatively well understood. In the last several years, many competitive results have been reported on bicrystal and step-edge Josephson junctions in YBa$_2$Cu$_3$O$_{y-8}$ (YBCO) thin films. Ti-based films show higher critical temperature $T_c$, 110–125 K, other parameters being comparable to those of YBCO and BiSCCO films. 4 The low-noise performance of the first Tl$_2$Ba$_2$CaCu$_2$O$_8$ (Tl-2212) dc superconducting quantum interference devices (SQUIDs) 5,6 was promising and stimulated further experiments. In this article we present and discuss results obtained on Tl-2212 Josephson junctions and dc SQUIDs on LaAlO$_3$ (LAO) bicrystal substrates.

II. DEVICE PREPARATION

The choice of a 32° angle grain boundary in our investigations was based on our previous experiments with YBCO, 7 and Tl-2212, 8 bicrystal junctions. The LAO bicrystal substrates were produced by the solid-phase intergrow ing method. 9 The Tl-2212 films were epitaxially grown by an ex situ method presented elsewhere. 10 Shortly, an amorphous precursor film was deposited on a bicrystal LAO substrate by pulsed laser ablation of a carbonate-free target with a nominal composition Ba$_2$CaCu$_2$O$_8$. The oxygen pressure was $2 \times 10^{-2}$ mbar and the deposition rate was 0.4 Å pulse. The precursor film was sealed inside a Tl-2212 crucible and annealed in Tl$_2$O atmosphere at high temperature. Films prepared under optimal conditions have $T_c$ varying from 105–109 K, the width of transition being 1–2 K. The films were epitaxial, c-axis oriented, with smooth background and small areas with trellislike structure. Φ scan indicated the absence of high-angle grain boundaries and the rocking curve has a full width at half-maximum (FWHM) of 0.37°. 11 The film thickness was about 300 nm.

Microbridges and dc SQUIDs were patterned by photolithography and Ar-ion-beam milling. Two microbridges, 5 and 10 μm wide, and a dc SQUID consisting of two 5-μm-wide microbridges in a $20 \times 20$ μm$^2$ loop crossed the grain boundary of the chip. In addition, two 5-μm-wide microbridges were placed on each half of the bicrystal to control the intragrain critical current density (see insert in Fig. 2). After patterning, $T_c$ was reduced by 1–2 K and the transition obtained a long tail (see the insert in Fig. 1). The dc SQUIDs were measured in a screened environment, using μ-metal and Nb superconducting shields.

III. RESULTS AND DISCUSSION

Figure 2 shows the $I$–$V$ characteristic of a Tl-2212 bicrystal junction. The $I$–$V$ curve exhibited RSJ-model behavior without hysteresis. Close to $T_c$ the $I$–$V$ curves were rounded by thermal noise and flux motion. The critical currents of the junctions were determined using a voltage criterion of 1 μV with no account for the rounding of the $I$–$V$ curves at high temperatures.
The temperature dependence of the normalized critical current $I_c/I_c^0$, $I_c^0$ being the critical current at 4.2 K, is shown in Fig. 3 for three junctions $J_1$, $J_2$, and $J_3$ all on one chip. The critical temperatures of the junctions $T_c$ are 105, 105.5, and 104.8 K, critical current densities at 77 K $I_c = 6 \times 10^3$, $4 \times 10^3$, and $2 \times 10^3$ A/cm$^2$, and characteristic voltage at 77 K $I_c R_n = 56$, 40, and 22 $\mu$V, respectively. Close to $T_c$, the temperature dependence of the normalized critical current can be described as $(1 - T/T_c)^2$, while at low temperature it is proportional to $(1 - 2T/T_c)$. The normal resistance $R_n$ decreases with decreasing the temperature and reaches a constant value at low temperature (see the insert in Fig. 3 showing $R_n$ as a function of $T/T_c$ for the junction $J_3$). This decrease in $R_n$ with $T$ is stronger than that observed for YBCO bicrystal junctions. The temperature dependencies of both $I_c$ and $R_n$ suggest that the junctions behave as superconductor–normal–metal–superconductor (SNS) weak links. The critical current densities and the normal resistances for these bicrystal junctions were comparable to those presented in Ref. 13.

The critical currents of the junctions vary with magnetic field with a maximum depression of 75% at 77 K.

The ac Josephson effect under external microwave radiation at 77 K is shown in Fig. 4(a) at different levels of microwave power. Shapiro steps up to $n=10$ appeared in the $I-V$ curves at the voltages of $n\hbar\nu/e$ (n is an integer, $\hbar$ is Planck’s constant) under microwave radiation with a frequency $\nu$ of 10.9 GHz. The dependence of the amplitude of the zeroth and the first steps on the microwave voltage are presented in Fig. 4(b). They can be described by Bessel functions [see the solid lines in Fig. 4(b)]. Some asymmetry and subharmonic phenomena were sometimes observed in the $I-V$ curves. This irregular behavior has not been understood clearly but might be connected to magnetic flux motion in a long Josephson junction. Alternatively, it can be ascribed to nonuniformity of the junction, as suggested in Refs. 14 and 15. We can not distinguish between the two possibilities as we did not systematically study junctions of different widths.

For the best device, the $I_cR_n$ product and the modulation voltage at 77 K were 40 and 16 $\mu$V. The inductance of the

FIG. 1. The temperature dependence of the resistance of a Tl-2212 bicrystal junction on a LAO substrate. The insert shows the long tail in the transition region.

FIG. 2. $I-V$ characteristic of the Tl-2212 bicrystal junction on a LAO substrate. The insert shows the layout of the chip.

FIG. 3. The temperature dependence of the normalized critical current $I_c/I_c^0$ for three Tl-2212 bicrystal junctions ($J_2$, $J_3$, and $J_5$) on one chip. $\Delta$ ($J_2$): 5-μm-wide junction; ◇ ($J_3$): 2×5 μm$^2$ dc SQUID; ○ ($J_5$): 10-μm-wide junction. The solid line corresponds to $I_c/I_c^0 \approx (1 - T/T_c)^2$. The insert shows the temperature dependence of the normal resistance for the junction $J_3$. The solid line is a guide to the eye.

FIG. 4. (a) Shapiro steps in $I-V$ curves of a Tl-2212 bicrystal junction under 10.9 GHz microwave radiation at 77 K and three different microwave powers. The amplitudes of the $n=0$ and $n=1$ steps vs microwave voltage are shown in (b); the solid lines are the zeroth and the first Bessel functions.
SQUID loop was estimated to be 80 pH and the parameter $\beta_I > 1$. The device was flux locked from 77 up to 94 K. The noise spectra of the dc SQUIDs were measured with a standard electronic setup having a noise level of 0.3 nV/\sqrt{Hz}. This corresponds to a flux noise level of $10 \mu \Phi_0/\sqrt{Hz}$. The optimum operating bias point for a device could be approached by adjusting the dc bias current of the junction and the applied dc magnetic field. The flux noise spectrum $S_\Phi(f)$ of the measuring system and the frequency response $S_V(f)$ were measured by a HP35663A dynamic analyzer in a locked-loop mode. The transfer function of the instrument was acquired with the shifting of one flux quantum in the output signal by varying the voltage in the input coil. The flux noise spectrum $S_\Phi(f)$ of the dc SQUID was calculated as

$$S_\Phi(f) = \frac{S_V(f)}{S_\Phi(f)} \frac{\partial \Phi}{\partial V}.$$  

Figure 5 shows the best flux noise spectrum $S_\Phi$ at 77 K, obtained in the locked-loop mode without bias reversing. The white noise level is $50 \mu \Phi_0/\sqrt{Hz}$. The low-frequency noise dominates below 5 Hz and the noise level at 1 Hz is $440 \mu \Phi_0/\sqrt{Hz}$. The TI-2212 dc SQUIDs in the present work may be compared to YBCO dc SQUIDs. The white noise of our devices is several times higher than that of the best YBCO SQUIDs, however, the low-frequency noise level is comparable for the two types of films.

IV. SUMMARY

TI-2212 weak links and dc SQUIDs made of epitaxial TI-2212 films on LAO bicrystal substrates with a misorientation angle of 32° were fabricated and studied. The $I-V$ curves of the junctions could be described by a RSJ model without hysteresis. The amplitude of Shapiro steps in the $I-V$ curves oscillate under microwave radiation showing a Bessel function behavior. Close to $T_c$, the temperature dependence of the critical current of the junctions can be fitted to $(1-T/T_c)^2$. The characteristics of the junctions indicate that they behave as SNS weak links. The work has shown that TI-2212 bicrystal dc SQUIDs have rather low $1/f$ noise. At the same time the white noise level does not reach the best values for YBCO devices yet. We believe that the potential of TI-based SQUIDs should be investigated further.

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